CSRI2×100-120

SIC SCHOTTKY DIODE TYPE 2×100A

Features

- High surge current capable
- Zero reverse recovery current VDC
- · High bandwidth
- Isolation type package
- Temperature independent switching behavior
- 1200 V
- 2×100 A • **I**F (Tc<135°C)

Benefits

- Unipolar rectifier
- Zero switching loss
- Smaller heat sink
- Parallel devices without thermal runaway
- Higher efficiency

Applications

- Motor drives
- Switch mode power supplies
- Ev chargers
- Solar inverters Welding equipment
- Power factor correction
- Diode snubber
- Automotive
- · induction heating

Maximum Ratings

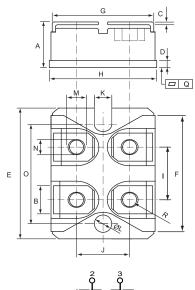
Operating Junction Temperature : - 55 $^{\circ}$ C to +175 $^{\circ}$ C

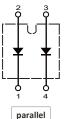
Storage Temperature : $-55 \,^{\circ}\text{C}$ to $+175 \,^{\circ}\text{C}$

Part Number	Maximum Recurrent Peak Reverse Voltage	Maximum DC Blocking Voltage
CSRI2×100-120	1200V	1200V

Maximum Rating	Symbol	Conditions	Value	Unit	
Continuous forward current (per diode)	I _F	T _C =135 °C	100		
Surge non-repetitive forward current	I _{FSM}	$T_{\rm C}$ =25 °C, $t_{\rm p}$ =8.3 ms	800		
sine halfwave (per diode)	1 014	T _C =150 °C, t _p =8.3 ms	500	Α	
Non-repetitive peak forward current	I _{F,max}	T_{C} =25 °C, t_{p} =10 μ s 3			
(per diode)		T_{C} =150 °C, t_{p} =10 μ s	2000		
Repetitive peak reverse voltage	V_{RRM}	T _j =25 °C	1200	V	
Isolation voltage (between all terminals and baseplate)	V _{iso}	50/60 Hz, t=1min I _{ISOL} ≤ 1mA	2500	V	
Mounting torque	M _d	To heatsink	1.3	Nm	
Mountaing torque	IVId	To terminal	1.1		







DIMENSIONS					
	INCHES		MM		
	MIN	MAX	MAX MIN		
Α	0.460	0.483	11.68	12.28	
В	0.307	0.323	7.80	8.20	
С	0.030	0.033	0.75	0.85	
D	0.071	0.081	1.80	2.05	
E	1.488	1.504	37.80	38.20	
F	1.248	1.260	31.70	32.00	
G	0.917	0.957	23.30	24.30	
Н	0.996	1.008	25.30	25.60	
I	0.579	0.602	14.70	15.30	
J	0.492	0.516	12.50	13.10	
K	0.161	0.169	4.10	4.30	
L	0.161	0.169	4.10	4.30	
M	0.181	0.197	4.60	5.00	
N	0.165	0.181	4.20	4.60	
0	1.181	1.197	30.00	30.40	
Q	-0.002	0.004	-0.05 0.10		
R	M4*8				

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Electrical Characteristics, at T_i=25 °C, unless otherwise specified. (per diode)

Static Characteristics	Symbol	Conditions	Values			
			min.	typ.	max.	Unit
DC blocking voltage	V _{DC}		1,200	-	-	
	V _F	I _F =100A, T _j =25 °C	-	1.6	1.8	V
Diode forward voltage	VF	I _F =100A, T _j =175 °C	-	2.4	2.9	
	l-	V _R =1,200V, T _j =25 °C	-	3.6	181	
Reverse current	I _R	V _R =1,200V, T _j =175 °C	-	230	2,300	μΑ

AC Characteristics (per diode)

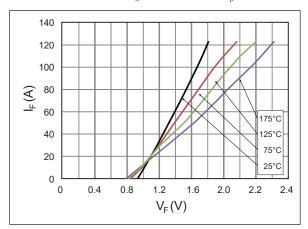
Static Characteristics	Symbol	Conditions	Values			
			min.	typ.	max.	Unit
Total capacitive charge	Q _{rr}	V _R =1,200V, T _j =25 °C	-	309	-	nC
Total capacitance	С	V _R =0V, f=1 MHz T _j =25 °C	-	5570	-	pF
		V _R =600V, f=1 MHz T _j =25 °C	-	553	-	
		V _R =1,000V, f=1 MHz T _j =25 °C	-	518	-	

Thermal Characteristics (per diode)

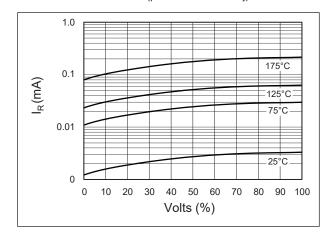
Static Characteristics	Cumbal	Values	Unit	
Static Characteristics	Symbol	typ.		
Thermal resistance from junction to case	$R_{ heta JC}$	0.14	°C/W	

Typical Performance

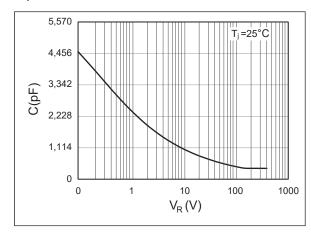
Forward Characteristics (parameterized on T_i)



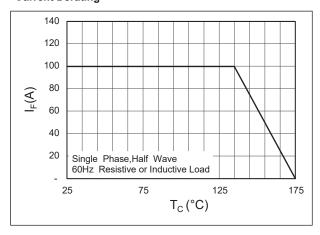
Reverse Characteristics (parameterized on Tj)



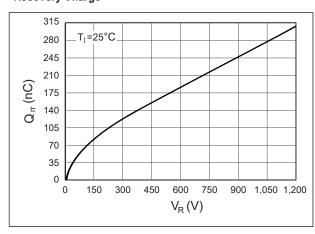
Capacitance



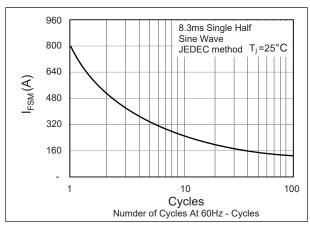
Current Derating



Recovery Charge



Forward Surge Current



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